

APPLICATION DATA SHEET

Electronic Version 0.0.11

Stylesheet Version: 1.0

Attorney Docket Number: BUR920010086

Publication Filing Type: new-utility

Application Type: utility

Title of Invention: FIN-BASED DOUBLE POLY DYNAMIC THRESHOLD CMOS FET WITH SPACER GATE AND METHOD OF FABRICATION

Customer Number Attorney: 30607



Customer Number Correspondence Address: 30607



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